NSN 5962-01-271-5534

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-271-5534 **Body Length:** 0.750 inches **Body Width:** 0.250 inches **Body Height:** 0.130 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -0.0/+70.0 degrees celsius **Storage Tempurature Range:** -55.0/+125.0 degrees celsius **Features Provided:** Dynamic and low power and monolithic **Inclosure Material: Plastic Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.0 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 120.00 nanoseconds propagation delay time, low to high level output and 120.00 nanoseconds propagation delay time, high to low level output **Memory Device Type: Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Yes - demil/mli

Demilitarization:

Fiig: A458a0